

2S7SIC D5.2UP series

2W - Dual Output - Wide Input - Isolated & Unregulated SiC dedicated DC-DC converter



DC-DC Converter

2 Watt



Temperature range: -40°C~+105°C

- Dual Output Voltage
- <table-cell-rows> 5200VDC Isolation voltage
- F Short circuit protection (SCP)
- Ultra low isolation capacitance
- Ultra Compact SIP package
- Good temperature characteristic
- RoHS Compliance
- SiC dedicated unregulated DC-DC converter
- No-load operation allowed

The 2STSIC_D5.2UP series are DC-DC converters for SiC MOSFETs. Their ultra low isolation capacitance can improve the capability of anti-interference. The built-in common-ground mode of the unique asymmetric voltage output mode reduces the driver loss of SiC MOSFETs. They feature short-circuit protection and autorecovery, and can be widely used in:

- General inverter
- · AC servo drive system
- · Electric welding machine
- Uninterruptible power supply (UPS)





Common specifications	
Short circuit protection:	Continuous, automatic recovery
Temperature rise at full load:	25°C TYP
Cooling:	Free air convection
Operation temperature range:	-40°C – +105°C
Storage temperature range:	-55°C – +125°C
Lead temperature	300°C MAX, 1.5mm from case for 10 sec
Storage humidity range:	< 95%
Case material:	Black flame-retardant and heat-resistant plastic [UL94-V0]
MTBF:	>3,500,000 hours
Weight:	4.3g

Input specificati	ons				
Item	Test condition	Min	Тур	Max	Units
Input voltage range	• 15V input • 12 input	13.5 10.8	15 12	16.5 13.2	VDC VDC
Hot plug	Unavailable				
Input filter	Capacitor				

Isolation specifications					
Item	Test condition	Min	Тур	Max	Units
Isolation voltage	Input-Output, tested for 1 minute and leakage current less than 1mA	5200			VDC
Isolation resistance	Input-Output, test at 500VDC	1000			ΜΩ
Isolation capacitance	Input/Output, 100KHz/0.1V		6.6		pF

Evample

2S7SIC_121503D5.2UP

2 = 2 Watt; S7 = SIP7; SIC = SiC serie; 12 = 12Vin;

15 = +15Vout; 03 = -3Vout; D = Dual Output; 5.2 = 5.2kVDC;

U = Unregulated; P = Short Circuit Protection (SCP)

Output specificati	ons				
Item	Test condition	Min	Тур	Max	Units
Output voltage	• +Vo: Vin=15VDC/12VDC, Pin6 & Pin7 +lo=+80mA	14.25	15	15.75	VDC
	 -Vo: Vin=15VDC/12VDC, Pin5 & Pin6 -lo=-40mA 	-8	-8.7	-9.4	VDC
	• +Vo: Vin=12VDC, Pin6 & Pin7 +lo=+93mA	14.25	15	15.75	VDC
	• -Vo: Vin=12VDC, Pin5 & Pin6 -lo=-185mA	-2.76	-3	-3.24	VDC
Output voltage accuracy	See tolerance envelope curve				
Line regulation	Input voltage range		±1.2	±1.5	%
Load regulation	10% to 100% load, positive output 10% to 100% load, negati- ve output		8 10	15 15	% %
Temperature drift coefficient	100% load			±0.03	%/°C
Ripple & Noise*	20MHz Bandwidth		100	200	mVp-p
Switching fre- quency	Full load, nominal input		100	300	KHz

^{*}Test ripple and noise by "parallel cable" method.

Note:

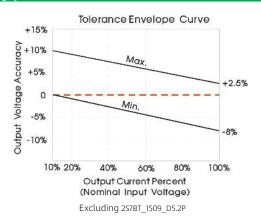
- The lead connecting the power supply module and SiC MOSFETs should be as short as possible during use;
- The output filtering capacitor should be as close as possible to the power supply module and SiC driver;
- The peak of the SiC MOSFETs gate drive current is high, so low internal resistance electrolytic capacitor is recommended to be used for the power supply module output filter capacitor;
- 4. The average output power of the driver must be lower than that of the power supply module;
- 5. Consider fixing with glue near the module if being used in vibration occasion;
- The max. capacitive load should be tested within the input voltage range and under full load conditions;
- 7. Unless otherwise noted, all specifications are measured at Ta = 25°C, humidity <75%, nominal input voltage and rated output load.
- 8. In this datasheet, all test methods are based on our corporate standards.
- 9. All characteristics are for listed models, and non-standard models may perform differently. Please contact our technical support for more detail.
- 10. Please contact our technical support for any specific requirement.
- 11. Specifications of this product are subject to changes without prior notice.

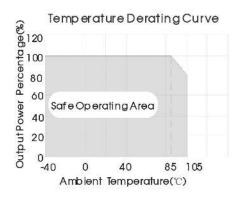
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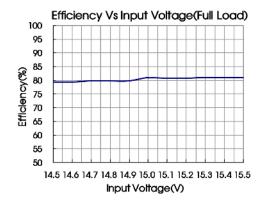
Part Number	Input Voltage [V]	Input current [mA, min/max]	Output Voltage [VDC, +Vo/-Vo]	Output current [mA, +Vo/-Vo]	Max. capacitive load [μF]	Efficiency [%, min]
1.4S7SIC_121505_D5.2UP	12	20/160	+15/-5.0	+80/-40	220	75-80
1.8S7SIC_241503D5.2UP	24	20/140	+15/-3.0	+111/+111	220	75-80
2S7SIC_121503_D5.2UP	12	20/160	+15/-3.0	+93/-185	220	75-80
2S7SIC_241503_D5.2UP	24	20/140	+15/-3.0	+66/-333	220	75-80
2S7SIC_122005_D5.2UP	12	20/160	+20/-5.0	+50/-200	220	75-80
2S7SIC_152005_D5.2UP	15	20/130	+20/-5.0	+50/-200	220	75-80
2S7SIC_242005_D5.2UP	24	30/140	+20/-5.0	+50/-200	220	75-80

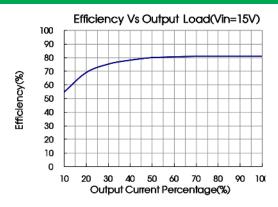
Typical characteristics





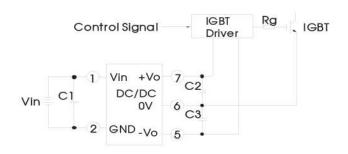
Efficiency





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Typical application

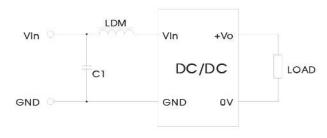


	C1/ C2 /C3
100uF/35\	(Low internal resistance capacitance)

Note: On both ends of capacitance C2 and C3 shunt respectively a capacitance value in 1uF-10uF ceramic capacitors.

EMC solution-recommended circuit

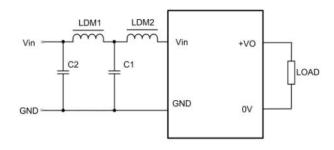
Recommended circuit 1



Input voltage (VDC)	12/15
EMI / C1	4.7μF/50V
EMI / LDM	12µH

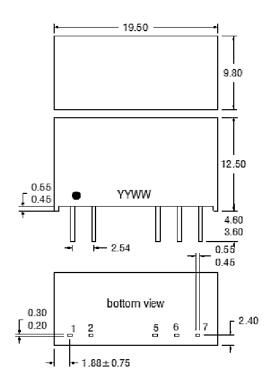
It is not allowed to connect modules output in parallel to enlarge the power.

Recommended circuit 2

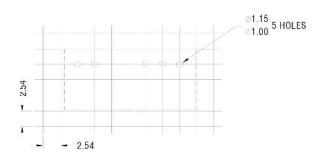


Input voltage (VDC)	12/15
EMI / C1, C2	4.7μF/50V
EMI / LDM1	12μΗ
EMI / LDM2	47μH

Mechanical dimensions



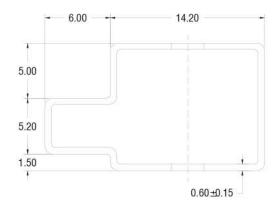
Weight: 4.3g All dimensions in mm ± 0.25 mm. All pins on a 2.54mm pitch and within ± 0.25 mm of true position.



All dimensions in mm±0.25mm

Output		
Pin	Function	
1	+Vin	
2	GND	
5	-Vout	
6	OV	
7	+Vout	

Tube outline dimensions



Unless otherwise stated all dimensions in ±mm ±0.5mm.

Tube length : 25mm±2mm.

Tube Quantity : 25